### SURFACE MOUNT DISPLAY

GaAs substrate Light Emitting Diode.

KPSC02-123

Description

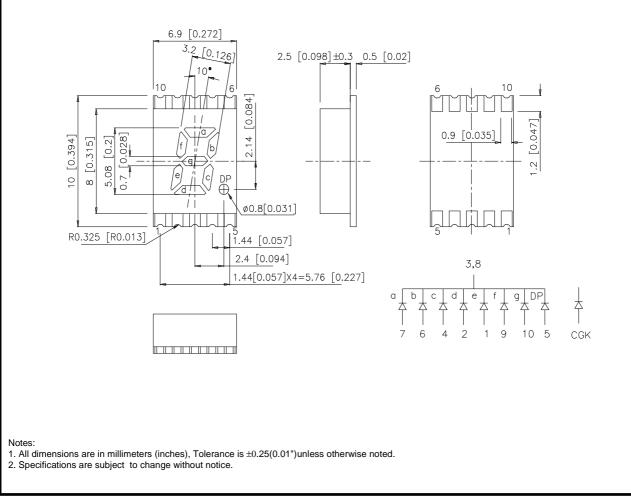
GREEN

The Green source color devices are made with InGaAIP on

#### Features

- •0.2INCH DIGIT HEIGHT.
- •LOW CURRENT OPERATION.
- •EXCELLENT CHARACTER APPEARANCE.
- •I.C. COMPATIBLE
- •MECHANICALLY RUGGED.
- •GRAY FACE, WHITE SEGMENT.
- •PACKAGE :1300PCS / REEL.

### Package Dimensions & Internal Circuit Diagram



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Selection Guide										
Part No.	Dice	Lens Type	lv (ucd) @ 10mA		Description					
			Min.	Тур.	• • • •					
KPSC02-123	GREEN (InGaAIP)	WHITE DIFFUSED	4700	26000	Common Cathode, Rt. Hand Decimal					

### Electrical / Optical Characteristics at TA=25°C

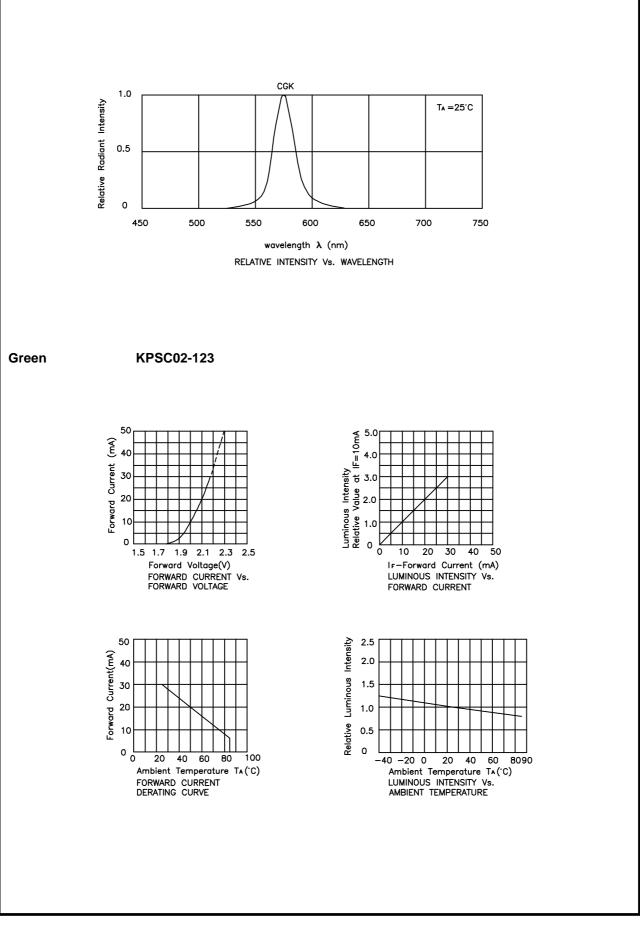
Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Green	574		nm	IF=20mA
λD	Dominant Wavelength	Green	570		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Green	20		nm	IF=20mA
С	Capacitance	Green	15		pF	VF=0V;f=1MHz
VF	Forward Voltage	Green	2.1	2.5	V	IF=20mA
IR	Reverse Current	Green		10	uA	VR = 5V

#### Absolute Maximum Ratings at TA=25°C

Parameter	Green	Units	
Power dissipation	105	mW	
DC Forward Current	30	mA	
Peak Forward Current [1]	150	mA	
Reverse Voltage	5	V	
Operating/Storage Temperature	ating/Storage Temperature -40°C To +85°C		

Note:

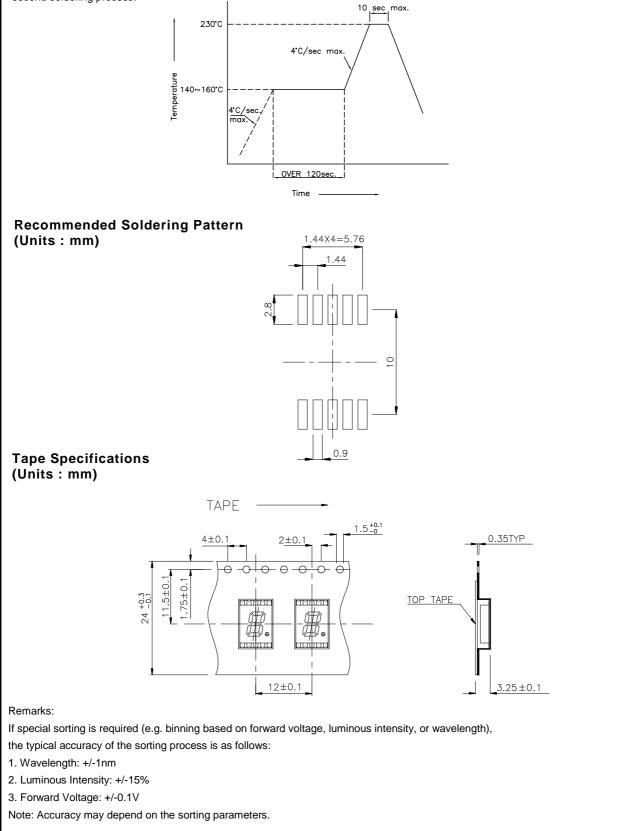
1. 1/10 Duty Cycle, 0.1ms Pulse Width.



#### KPSC02-123 SMT Reflow Soldering Inc

### SMT Reflow Soldering Instructions

Number of reflow process shall be 2 times or less and cooling process to normal temperature is required between first and second soldering process.



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